

Listing of the Claims

1. (Original) An emitter, comprising:

an electron supply;

a tunneling layer disposed on the electron supply;

a cathode layer disposed on the tunneling layer; and

a conductive electrode having multiple layers of conductive material

including a protective layer disposed on the cathode layer and wherein the
conductive electrode has been etched to define an opening thereby exposing a
portion of the cathode layer.

2. (Original) The emitter of claim 1 wherein the protective layer is titanium or
molybdenum.

3. (Original) The emitter of claim 1 wherein the protective layer has a thickness
about 300 to about 1500 Angstroms.

4. (Original) The emitter of claim 1 wherein the cathode layer includes gold,
tantalum, platinum, or combinations thereof.

5. (Original) The emitter of claim 1, further comprising;

an electron lens for focusing electrons emitted from the exposed portion of
the cathode layer.

6. (Original) The emitter of claim 1, wherein the protective layer is a first protective layer and the conductive electrode is a first conductive electrode, the emitter further comprising:

5 a second protective layer disposed on the first conductive electrode and defining an opening in substantial alignment with the opening of the first conductive electrode;

a spacer layer disposed on the second protective layer and defining an opening in substantial alignment with the opening of the first conductive electrode; and

10 a second conductive electrode disposed on the spacer layer and defining an opening in substantial alignment with the opening of the conductive electrode.

7. (Original) An integrated circuit, comprising:

a substrate;

15 at least one emitter of claim 1 disposed on the substrate; and

circuitry formed on the substrate with the emitter for operating the at least one emitter.

8. (Original) An electronic device, comprising:

20 the emitter of claim 1 for emitting energy; and

an anode structure for receiving the emitted energy and generating at least a first effect in response to receiving the emitted energy and a second effect in response to not receiving the emitted energy.

25 9. (Original) The electronic device of claim 8 wherein the electronic device is a mass storage device and the anode structure is a storage medium, the electronic device further comprising a reading circuit for detecting the effect generated on the anode structure.

30 10. (Original) The electronic device of claim 8 wherein the electronic device is a display device and the anode structure is a display screen that creates a visible effect in response to receiving the emitted energy.

11. (Original) The electronic device of claim 10 wherein the display screen includes one or more phosphors operable for emitting photons in response to receiving the emitted energy.

5 12. (Currently Amended) An emitter, comprising:

a cathode layer having an emissive surface;

an electron lens disposed at a predetermined distance from the emissive surface;

10 a spacer layer of tetraethylorthosilicate, silicon oxides, silicon nitrides, or combinations thereof separating the electron lens and emissive surface; and

at least one sacrificial layer disposed between the cathode layer and the electron lens, the at least one sacrificial layer having an opening substantially aligned with said emissive surface.

15 13. (Original) The emitter of claim 12 wherein the at least one sacrificial layer is titanium or molybdenum.

Claims 14-16 (Cancelled).

20 17. (Original) An emitter, comprising:

an electron supply;

a tunneling layer formed on the electron supply;

a cathode layer formed on the tunneling layer; and

25 a conductive protective layer disposed on the cathode layer wherein the conductive protective layer has been etched to define an opening thereby exposing a portion of the cathode layer for electron emission.

18. (Original) The emitter of claim 17 capable of emitting photons in addition to the electron emission.

30 19. (Original) A display device using the emitter of claim 17 to form a portion of an image from the emitted photons.

20. (Original) The emitter of claim 17 wherein the conductive protective layer has been etched with sulfuric peroxide.

21. (Original) The emitter of claim 17 further comprising a lens structure formed
5 on the conductive protective layer before the conductive protective layer is etched.

22. (Original) The emitter of claim 21 wherein the lens structure comprises a spacer layer formed of tetraethylorthosilicate, silicon oxides, silicon nitrides, or combinations thereof.

10 23. (Original) A display device, comprising:

an integrated circuit including the emitter of claim 17, wherein the emitter creates a visible light source; and

a lens for focusing the visible light source, wherein the lens is coated with a
15 transparent conducting surface to capture electrons emitted from the emitter.

24. (Original) A storage device, comprising:

an integrated circuit including the emitter of claim 17 wherein the emitter creates a focused electron beam; and

20 a storage medium in close proximity to the emitter, the storage medium having a storage area being in one of a plurality of states to represent the information stored in that storage area;

such that:

an effect is generated when the focused electron beam strikes the
25 storage area;

the magnitude of the effect depends on the state of the storage area;

and

the information stored in the storage area is read by measuring the magnitude of the effect.

30 25. (Original) An electronic device, comprising:

an integrated circuit including the emitter of claim 17; and

a focusing device for converging the emissions from the emitter.

26. (Original) A computer system, comprising:

a microprocessor;

the electronic device of claim 25 coupled to the microprocessor; and

memory coupled to the microprocessor, the microprocessor operable of

executing instructions from the memory to transfer data between the memory and the electronic device.

27. (Original) The computer system of claim 26 wherein the electronic device is a storage device.

28. (Original) The computer system of claim 26 wherein the electronic device is a display device.

29. (Original) An emitter, comprising:

a substrate;

an insulator layer formed on the substrate and having a first opening defined within;

an emission layer disposed over the insulator layer and first opening and contacting the substrate;

a tunneling layer formed on the emission layer;

a cathode layer disposed on the tunneling layer wherein a portion of the cathode layer on the tunneling layer is an electron-emitting surface; and

a conductive protective layer disposed on the cathode layer and defining a second opening substantially aligned with the first opening.

30. (Original) The emitter of claim 29 wherein the electron emitting surface has an emission rate of about 0.1 to about 8.0 Amps per square centimeter.

31. (Original) The emitter of claim 29 wherein the protective layer is formed of titanium or molybdenum.

32. (Original) The emitter of claim 29 wherein the emission layer is formed of polysilicon.

33. (Original) The emitter of claim 29 further comprising an electron lens disposed a first distance from the electron-emitting surface.

34. (Original) The emitter of claim 33 further comprising a spacer layer of
5 tetraethylorthosilicate, silicon oxides, silicon nitrides, or combinations thereof disposed between the electron lens and the protective layer.

35. (Original) The emitter of claim 34 wherein the stress created between the spacer layer and the cathode layer is less than an absolute value of about 100
10 mPascals.

36. (Original) The emitter of claim 34 wherein the spacer layer etch rate and the protective layer etch rate have an etch selectivity at least about 10:1.

37. (Original) The emitter of claim 29 wherein the protective layer has been
15 etched with sulfuric peroxide or ammonia and water to create the defined opening within the protective layer.

38. (Original) The emitter of claim 37 wherein the sulfuric peroxide etch is
20 performed using about 1 part H₂O and about 2 parts H₂SO₄.

39. (Original) An integrated circuit comprising at least one emitter of claim 29.

40. (Original) A display device comprising at least one emitter of claim 29.

41. (Original) A storage device comprising at least one emitter of claim 29.

42. (Original) An electronic device comprising at least one emitter of claim 29.

43. (Original) An integrated circuit, comprising:

a substrate;

at least one emitter formed on the substrate including,

an insulator layer having at least one opening to define the location and

5 shape of the at least one flat emitter device,

an emission layer disposed within the at least one opening of the insulator layer and further disposed over the insulator layer;

a tunneling layer disposed over the emission layer;

a cathode layer disposed over the tunneling dielectric; and

10 a protective layer disposed over cathode layer, the protective layer having at least one opening in substantial alignment with the at least one opening of the insulator layer.

44. (Original) The integrated circuit of claim 43 wherein the protective layer is

15 comprised of titanium or molybdenum of about 300 to about 1500 Angstroms in thickness.

45. (Original) The integrated circuit of claim 44 wherein the emission layer is formed of polysilicon.

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46. (Original) The integrated circuit of claim 45 wherein the tunneling layer is comprised of thermal oxide grown from polysilicon layer.

47. (Original) The integrated circuit of claim 44 further comprising an electron lens

25 disposed on the at least one emitter.

Claims 48-69 (Cancelled)